

Ito-Langevin Model and Stochastic Thermodynamics Overview

Graphene-based Energy Harvesting
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Langevin Equation of Brownian Particle

Langevin Equation for Charge through Equivalent Resistor

Fokker-Planck Equation

Average Generated Power

Simulation

Equilibrium Average of Generated Power

Langevin Equation of Brownian Particle

- ▶ $\mathcal{H}(x, p, q) = \frac{p^2}{2m} + U(x) + \frac{q^2}{2C(x)} - \frac{C_0(V)V^2}{2d}x + qV$
- ▶ From Hamilton's Equations:

$$dx = v dt$$

$$mdv = \left[-\eta v - U'(x) - \frac{q^2 - C_0 V^2}{2C_0 V d} \right] dt + \sqrt{2T\eta} dw_p$$

Langevin Equation for Charge through Equivalent Resistor

- ▶ Some relations used later on:

$$\frac{\partial \mathcal{H}}{\partial q} = V + \frac{q}{C(x)}$$

- ▶ Langevin Equation:

$$dq = \left[\frac{\partial}{\partial q} \left(\frac{T}{\mathcal{R}} \right) - \frac{1}{\mathcal{R}} \frac{\partial \mathcal{H}}{\partial q} \right] dt + \sqrt{\frac{2T}{\mathcal{R}}} dw_q$$

Fokker-Planck Equation

- In general:

$$\frac{\partial \rho}{\partial t} = \sum_{i,j} \frac{\partial}{\partial A_i} \left(-k_B T [A_i, A_j] + \lambda_{ij} \frac{\partial \mathcal{H}}{\partial A_j} + \lambda_{ij} \frac{\partial}{\partial A_j} \right) \rho(\mathbf{A}, t)$$

- Our case:

$$\begin{aligned} \frac{\partial \rho}{\partial t} = & -\frac{\partial}{\partial x} \left(\frac{\partial \mathcal{H}}{\partial p} \rho \right) + \frac{\partial}{\partial p} \left[\frac{\partial \mathcal{H}}{\partial x} \rho + \eta \left(\frac{p}{m} \rho + T \frac{\partial \rho}{\partial p} \right) \right] + \\ & \frac{\partial}{\partial q} \left[\frac{1}{\mathcal{R}} \left(\frac{\partial \mathcal{H}}{\partial q} \rho + T \frac{\partial \rho}{\partial q} \right) \right] \end{aligned}$$

Solution to FPE

- ▶ constant Equivalent Resistance \mathcal{R}
- ▶ Stationary Solution is the Equilibrium Probability Density when

$$\frac{\partial \rho}{\partial t} = 0$$

$$\rho_0(\mathbf{A}) = \text{const} \times e^{\frac{-\mathcal{H}}{T}}$$

Average Generated Power

► POV of Graphene Ripple

$$\begin{aligned} d'Q &= \left(-\eta \frac{p}{m} + \sqrt{2T\eta} \frac{dw_p}{dt} \right) \circ dx(t) \\ &= d\mathcal{H}(x, p, q) - \frac{\partial \mathcal{H}}{\partial q} \circ dq(t) \end{aligned}$$

► Converting to an Ito Product:

$$d'Q = \frac{\eta}{m^2} (mT - p^2) dt + \sqrt{2T\eta} \frac{p}{m} dw_p(t)$$

Averages

- ▶ Average Heat Flux vanishes in equilibrium because of equipartition theorem

$$\left\langle \frac{d'Q}{dt} \right\rangle = \frac{\eta}{m} \left(T - \left\langle \frac{p^2}{2m} \right\rangle \right)$$

- ▶ Average power absorbed by the particle

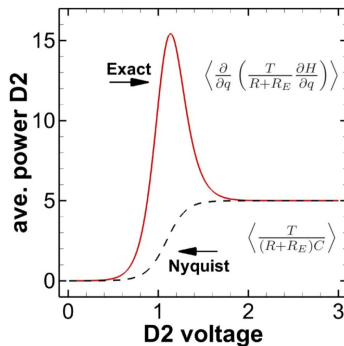
$$\left\langle \frac{d'W}{dt} \right\rangle = \left\langle \frac{\partial}{\partial q} \left(\frac{T}{\mathcal{R}} \frac{\partial \mathcal{H}}{\partial q} \right) \right\rangle - \left\langle \frac{1}{\mathcal{R}} \left(\frac{\partial \mathcal{H}}{\partial q} \right)^2 \right\rangle$$

Quantities used for Simulation

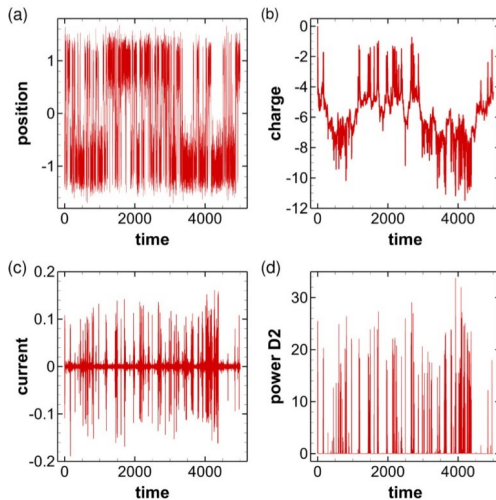
- ▶ Ripple Height, $l = 1 \text{ nm}$
- ▶ Distance between graphene and STM Tip, $d = 10l$
- ▶ Acoustic Phonon Frequency, $\eta/m = 1 \text{ THz}$
- ▶ Saturation Current, $I_0 = 1 \text{ nA}$
- ▶ Capacitance for Tip-Graphene Junction, $C_0 = 1 \text{ fF}$

Simulation

► Nyquist result vs Exact Result



Simulation



Simulation

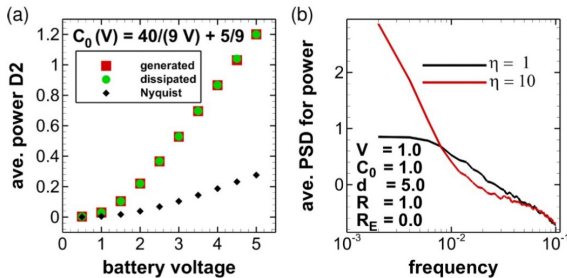


FIG. 6. Ito-Langevin equation simulation results for a circuit with diodes and resistor. (a) Average counterclockwise power versus battery voltage. (b) Average power spectrum density of power vs. frequency.

Equilibrium Average of Generated Power

- ▶ *“The overall equilibrium power due to the electric circuit is zero because the dissipated power at diodes and resistor are compensated exactly by the power generated by thermal fluctuations”*